

F20C05 Thru F20C20

Switchmode Dual Fast Recovery Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- *Glass Passivated chip junctions
- *Low Reverse Leakage Current
- $\ast\, {\rm Fast}$ Switching for High Efficiency
- $*150^{\circ}$ C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- $\ast \operatorname{Low}$ Forward Voltage , High Current Capability
- * Plastic Material used Carries Underwriters Laboratory
- * Flammability Classification 94V-O



* Pb Free

* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic	istic Symbol F20C Uni	l lm it				
Characteristic		05	10	15	20	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	V
Average Rectifier Forward Current Per Leg $T_C=125^{\circ}C$ Per Total Device	I _{F(AV)}		-	0 0		A
Peak Repetitive Forward Current (Rate V_R , Square Wave, 20kHz)	I _{FM}		2	0		A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}		17	75		A
Operating and Storage Junction Temperature Range	T _J , T _{stg}		-65 to	+150		°C

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	F20C				Unit
		05	10	15	20	Unit
Maximum Instantaneous Forward Voltage (I_F =10 Amp T_C = 25 $^\circ\!\!\!\mathrm{C}$)	V _F	1.30			V	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_c = 25^{\circ}C$) (Rated DC Voltage, $T_c = 125^{\circ}C$)	I _R	10 200			uA	
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0,I _{rr} =0.25 A)	T _{rr}	150			ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	CP	55		РF		

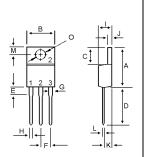


FAST RECOVERY

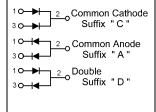
RECTIFIERS

20 AMPERES

50-200 VOLTS

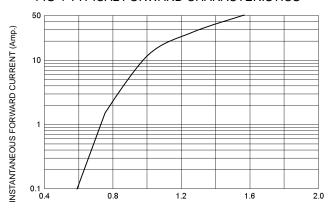


DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	14.68	16.00		
В	9.78	10.42		
С	5.02	6.60		
D	13.00	14.62		
Е	3.10	4.19		
F	2.41	2.67		
G	1.10	1.67		
Н	0.69	1.01		
Ι	3.21	4.98		
J	1.14	1.40		
К	2.20	3.30		
L	0.28	0.61		
М	2.48	3.00		
0	3.50	4.00		

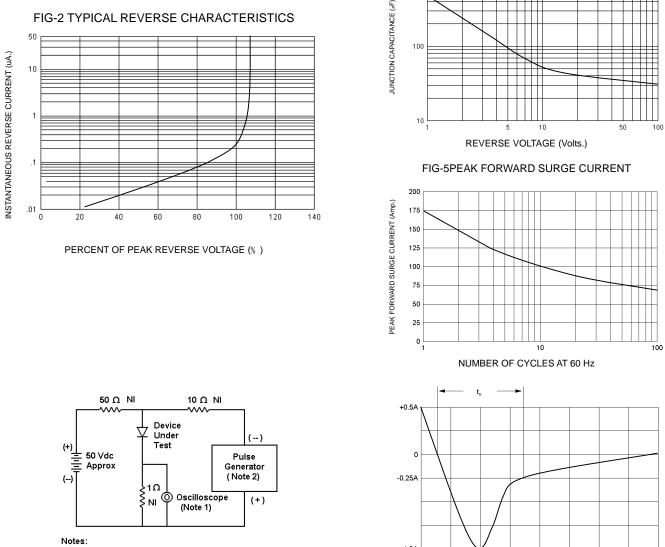


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FIG-1 TYPICAL FORWARD CHARACTERISTICS



FORWARD VOLTAGE (Volts)



1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

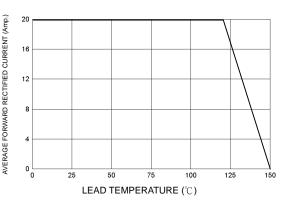
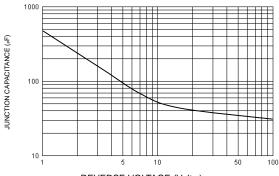
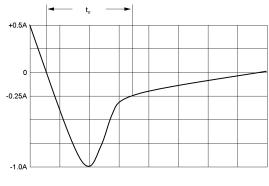


FIG-4TYPICAL JUNCTION CAPACITANCE





Set time base for 20/50 ns/cm FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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